

30V P-Channel Enhancement Mode MOSFET

Description	Schematic diagram
<p>The CP30P03QR uses advanced trench technology to provide excellent $R_{DS(ON)}$. This device is suitable for use as a load switch or in PWM applications.</p>	
General Features	Marking and pin assignment
<ul style="list-style-type: none"> ◆ $V_{DS} = -30V$, $I_D = -30A$ $R_{DS(ON)}(\text{Typ.})=11.2\text{m}\Omega$ @ $V_{GS}=-10V$ $R_{DS(ON)}(\text{Typ.})=15.3\text{m}\Omega$ @ $V_{GS}=-4.5V$ ◆ High power and current handing capability ◆ Lead free product is acquired ◆ Surface mount package ◆ 150 °C operating temperature ◆ 100% UIS tested 	<p>PDFN3×3-8L (Top View)</p>
Application	
<ul style="list-style-type: none"> ◆ PWM applications ◆ Load switch ◆ Uninterruptible power supply 	
Package	
<ul style="list-style-type: none"> ◆ PDFN3×3-8L 	

Ordering Information

Part Number	Storage Temperature	Package	Devices Per Reel
CP30P03QR-G	-55°C to +150°C	PDFN3×3-8L	5000

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

parameter	symbol	limit	unit
Drain-source voltage	V_{DS}	-30	V
Gate-source voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-30	A
		-22	
Pulsed Drain Current	I_{DP}	-120	A
Avalanche energy($T_j=25^\circ C$, $V_{DD}=15V$, $V_G=10V$, $L=0.5\text{mH}$, $R_g=25\Omega$)	E_{AS}	93.7	mJ
Power Dissipation	P_D	23	W
		15	
Operating junction Temperature range	T_j	-55—150	°C

Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _D =-250μA	-30	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	μA
		T _J =55°C	-	-	-5	
Gate Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1.0	-1.5	-2.5	V
Drain-source on-state resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-3A	-	11.2	14	mΩ
		V _{GS} =-4.5V, I _D =-2A	-	15.3	19	
On Status Drain Current	I _{D(ON)}	V _{DS} =-5V, V _{GS} =-10V	-30	-	-	A
Diode Characteristics						
Diode Forward Voltage	V _{SD}	I _{SD} =-3A, V _{GS} =0V	-	-0.75	-1.2	V
Diode Continuous Forward Current	I _S		-	-30	-	A
Reverse Recovery Time	t _{rr}	I _F =-30A, dI/dt=-100A/us	-	25	-	ns
Reverse Recovery Charge	Q _{rr}		-	18	-	nC
Dynamic Characteristics						
Gate Resistance	R _G	V _{GS} =0V, V _{DS} =0V, f=1MHz	-	13.8	-	Ω
Input capacitance	C _{iss}	V _{GS} =0V, V _{DS} =-15V f=1.0MHz	-	1440	-	pF
Output capacitance	C _{oss}		-	194	-	
Reverse transfer capacitance	C _{rss}		-	147	-	
Turn-on delay time	t _{D(ON)}	V _{GS} =-10V, V _{DS} =-15V, R _L =1.6Ω, I _D =3A, R _G =3Ω	-	11	-	ns
Turn-on Rise time	t _r		-	9.4	-	
Turn-off delay time	t _{D(OFF)}		-	24	-	
Turn-off Fall time	t _f		-	12	-	
Total gate charge	Q _g	V _{GS} =-10V, I _D =-3A V _{DS} =-15V	-	27	-	nC
Gate-source charge	Q _{gs}		-	4.6	-	
Gate-drain charge	Q _{gd}		-	4.6	-	

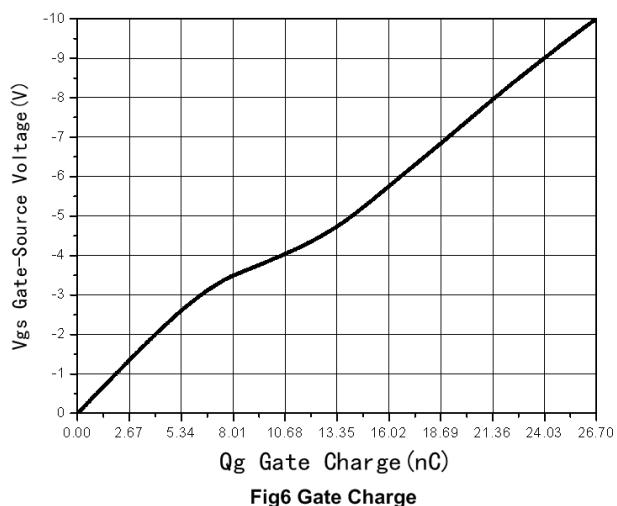
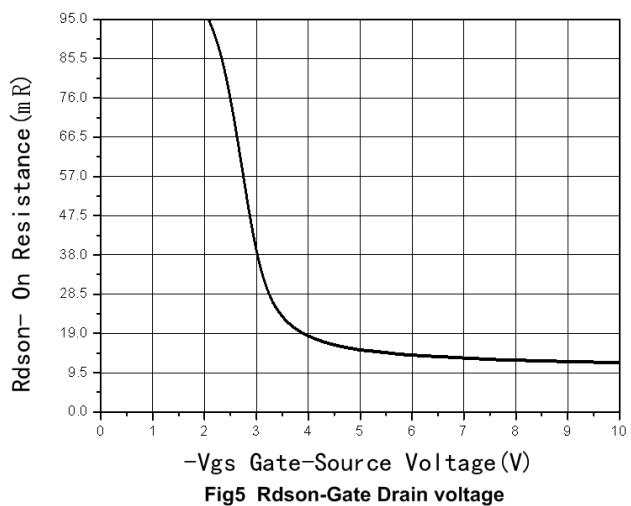
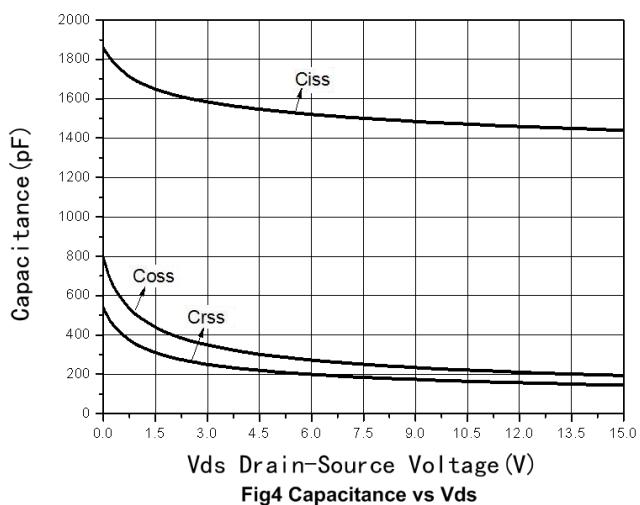
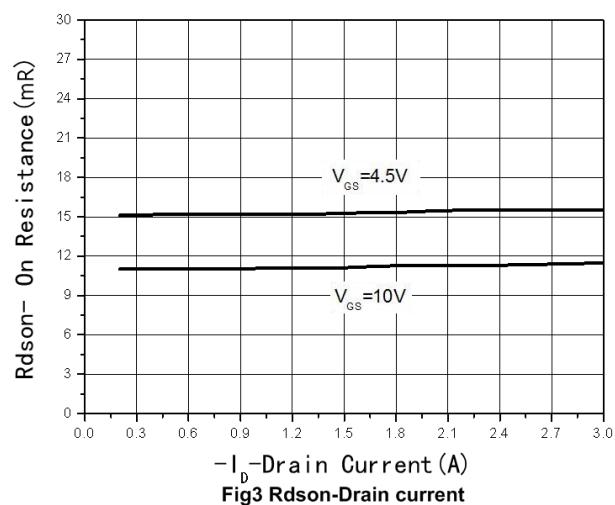
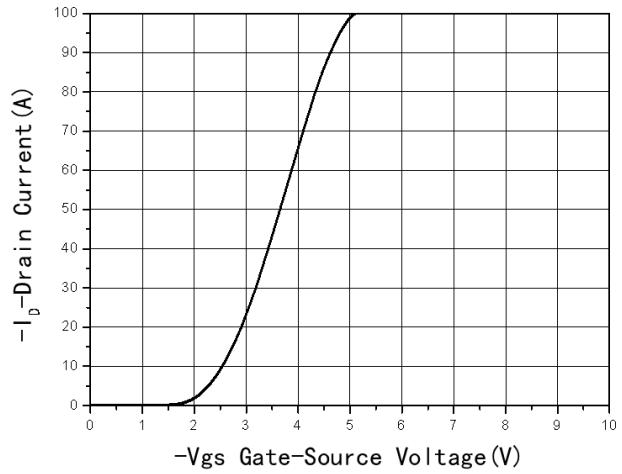
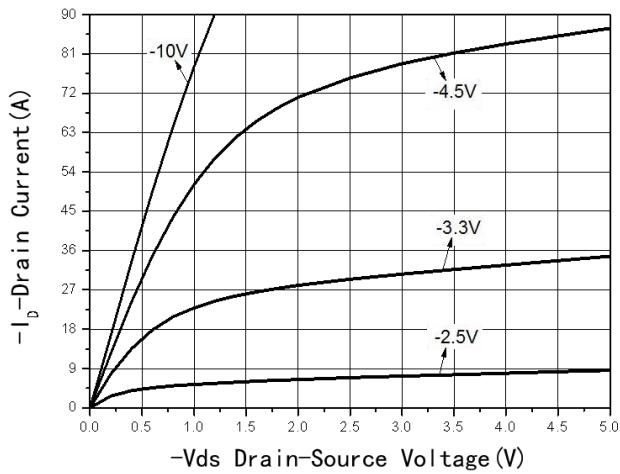
Thermal Characteristics

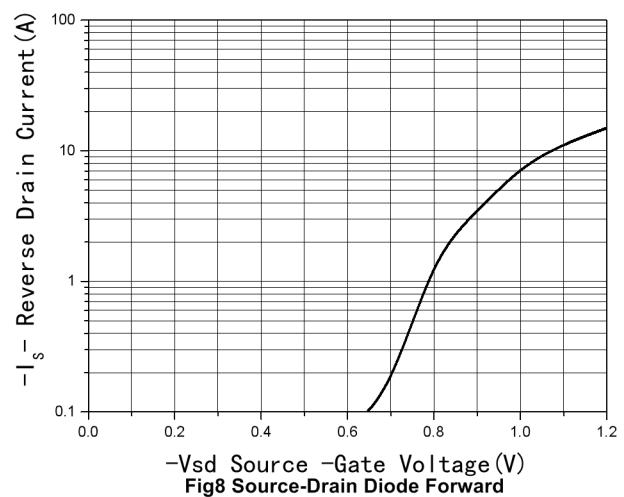
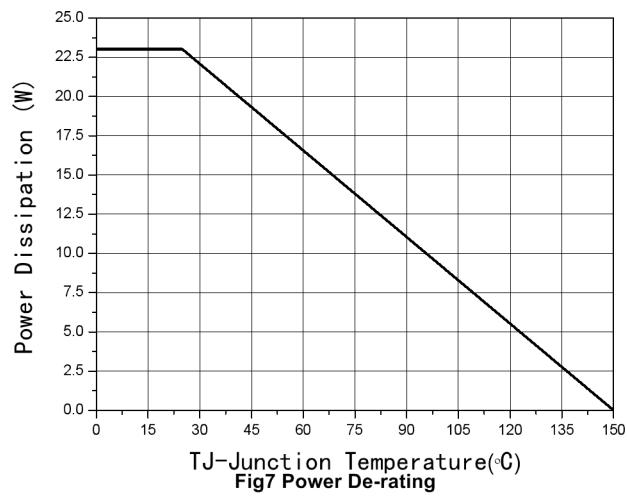
Parameter	Symbol	Typ	Max	Unit
Maximum Junction-to-Ambient ^A	R _{θJA}	29	34	°C/W
Maximum Junction-to-Ambient ^A		56	66	
Maximum Junction-to-Lead ^B		3.5	4.2	

A: The value of R_{θJA} is measured with the device mounted on 1in 2 FR-4 board with 2oz. Copper, in a still air environment with T A=25°C. The value in any given application depends on the user's specific board design. The current rating is based on the t ≤ 10s thermal resistance rating.

B: The R_{θJA} is the sum of the thermal impedance from junction to lead R_{θJL} and lead to ambient.

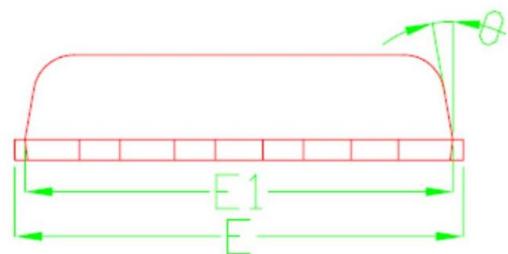
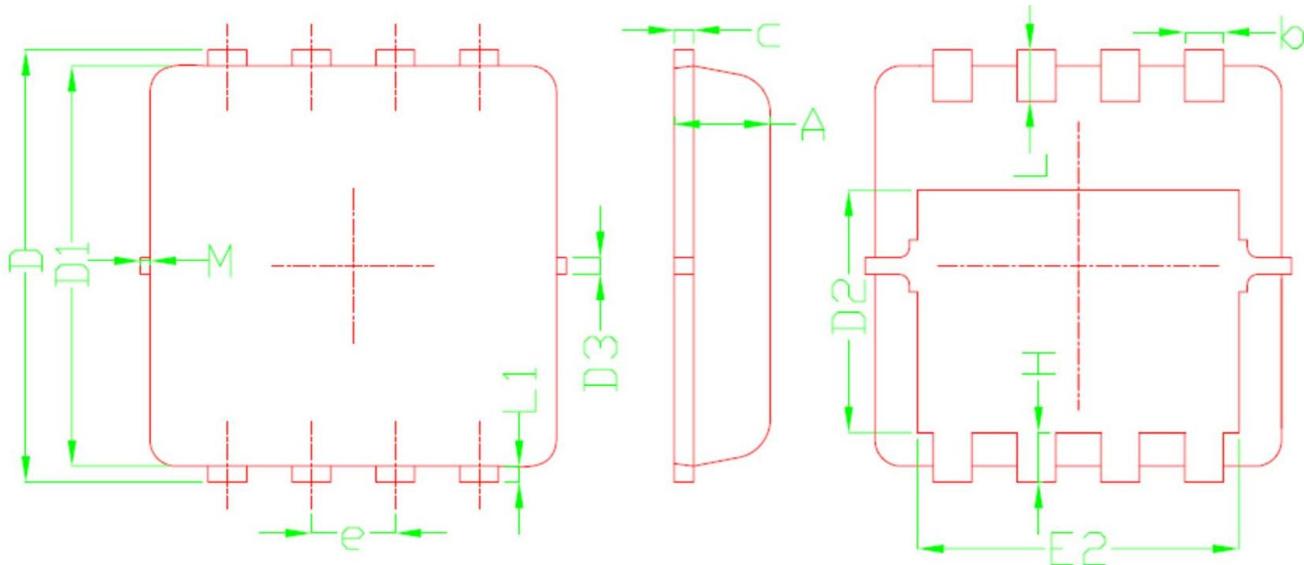
Typical Performance Characteristics



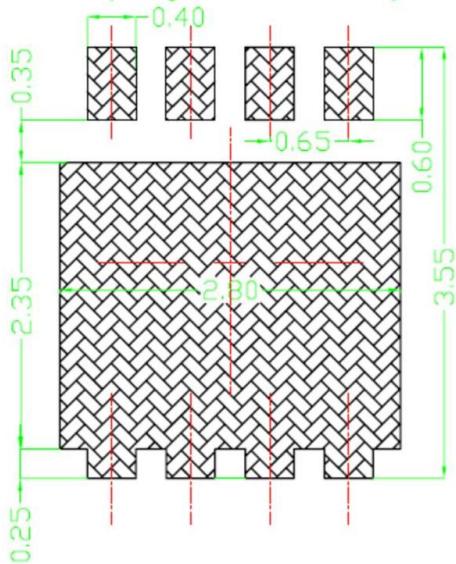


Package Information

- PDFN3*3-8L



**Land Pattern
(Only for Reference)**



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
b	0.25	0.30	0.35
c	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.78	1.88	1.98
D3	---	0.13	---
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65BSC		
H	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	---	0.13	---
θ	---	10°	12°
M	*	*	0.15
<i>* Not specified</i>			